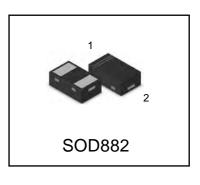
SEMICONDUCTOR TECHNICAL DATA

FTVL05BUL2

ESD PROTECTION DIODE

Discription

The FTVL05BUL2 is designed to protect voltage sensitive components from ESD. Excellent clamping capability, low leakage, and fast response time ,make these parts ideal for ESD protection on designs where board space is at a premium. Because of its small size, it is suited for use in cellular phones, MP3 players, digital cameras and many other portable applications where board space is at a premium.





Applications

- Cellular phones audio
- MP3 players
- Digital cameras
- Portable applicationss
- mobile telephone

Features

- Low Leakage
- Response Time is Typically < 1 ns
- ESD Rating of Class 3 (> 16 kV) per Human Body
 Model
- IEC61000-4-2 Level 4 ESD Protection
- We declare that the material of product compliant with RoHS requirements and Halogen Free.

Ordering information

| Device | Marking | Shipping | | |
|------------|---------|-----------------|--|--|
| FTVL05BUL2 | Q4 | 10000/Tape&Reel | | |

MAXIMUM RATINGS

| Rating | Symbol | Value | Unit |
|---|---------|------------|----------|
| IEC 61000-4-2 (ESD) Air discharge Contact discharge | | ±15 ±8 | kV kV |
| ESD Voltage Per Human Body Model | | 16 | kV |
| Total Power Dissipation on FR-5 Board (Note 1) | PD | 200 | mW |
| @ T _A =25 | | | |
| Junction and Storage Temperature Range | TJ,TSTG | -55 to 150 | |
| Lead Solder Temperature – Maximum (10 | TL | 260 | |
| Second Duration) | | | |

Stresses exceeding Maximum Ratings may damage the device. Maximum Rating are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. FR-5 = 1.0*0.75*0.62 in.

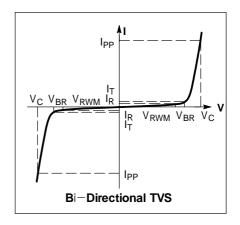
FTVL05BUL2



ELECTRICAL CHARACTERISTICS

 $(T_A = 25^{\circ}C)$ unless otherwise noted)

| Symbol | Parameter | | | | | |
|-----------------|--|--|--|--|--|--|
| I _{PP} | Maximum Reverse Peak Pulse Current | | | | | |
| V _C | Clamping Voltage @ IPP | | | | | |
| V_{RWM} | Working Peak Reverse Voltage | | | | | |
| I _R | Maximum Reverse Leakage Current @ VRWM | | | | | |
| V_{BR} | Breakdown Voltage @ IT | | | | | |
| I _T | Test Current | | | | | |
| P_{pk} | Peak Power Dissipation | | | | | |
| С | Capacitance @ VR = 0 and f = 1.0 MHz | | | | | |



ELECTRICAL CHARACTERISTICS

| | V _{RWM} (V) | I _R (uA) @ V _{RWM} | V _{BR} (V) @ IT (Note 2) | I _T | V _C (V) @ I _{PP} = 1A (Note 3) | V _C (V) @MAX I _{PP} (Note 3) | I_{PP}(A) (Note 3) | P _{PK} (W) (Note 3) | C (pF) | |
|------------|-------------------------|---|--------------------------------------|----------------|--|--|--------------------------------------|---------------------------------|--------|-----|
| Device | Max | Max | Min | mA | Max | Max | Max | Max | Тур | Max |
| FTVL05BUL2 | 5 | 0.5 | 6 | 1.0 | 12 | 20 | 4 | 80 | 0.25 | 0.3 |

Other voltage available upon request.

- 3. Surge current waveform per Figure 1.

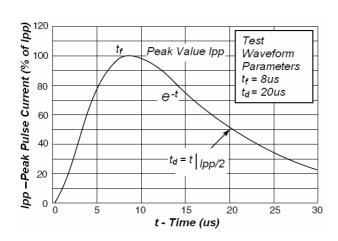


Fig1. Pulse Waveform

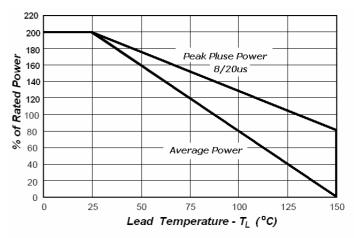


Fig2.Power Derating Curve

2/3



SOD882

DIMENSION OUTLINE:

Unit:mm

